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Abstract- Plasma is a state of matter which contains free (not bound to an atom) charged particles (electrons and ions). It is the ionized gas and hence affected by electric and magnetic field. This paper focuses on design and analysis of sensor to diagnose and measure plasma properties. The sensor is Langmuir probe was made and operated to determine current-Voltage characteristics of plasma, its electron density, ion density, temperature and other properties of the plasma. Designed probe was calibrated and results are analyzed by theoretical calculations and also benchmarked with reported literature.


1. INTRODUCTION

Langmuir probe is a diagnostic tool, a metallic probe to diagnose the Plasma. The probe gives the characteristics of the plasma in absence of external interference. It is used for measuring electron temperature, electron density, floating potential, ion saturation current. By varying the bias voltage of the probe, the current–voltage characteristics were measured and electron temperature, electron density and electron saturation current were calculated. These measurements are important to study plasma characteristics. Maxwell- Boltzmann distribution is a theoretical calculation limit which is achieved if the whole plasma and its surroundings are in complete thermodynamic equilibrium. Hence some deviation from the theoretical curve is expected in experiment.

The current voltage characteristics are mainly divided in three regions:

Region 1: By applying negative bias voltage across the Langmuir probe positive ions are collected on the tip of Langmuir probe which gives a change in voltage across the resistor is known as ion saturation current (Iₛᵢ).

Region 2: In this region bias voltage is kept positive and is varied up to plasma potential. This region is called as the Electron retardation region, with linear line between the bias voltage and probe current. Flow of positive ions and electrons are equal results in net zero current.

Region 3: In this region, bias voltage is greater than the plasma potential (V>Vₛ). The electrons get accelerated due to the positive bias voltage.

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³ Mr. DBV Singh is Asst. Prof. in ITM University, Gwalior, E-mail: dbvsingh@gmail.com
Input Parameters:
DC Power Supply, Nitrogen gas, Vacuum.

Output Calculated:
Probe current, current-Voltage characteristics, Electron temperature, electron density, electron Saturation current and floating potential.

2. Langmuir Probe Design and construction-
Langmuir Robe works by inserting one or more electrode into the plasma and observing the current to the probe as a function of difference between the probe and the plasma space potential can determine the basic Plasma parameters.

a. Probe Types:
There are three methods of Plasma diagnostics and plasma parameter measurement using Langmuir probes namely

1. Single Langmuir Probe :
Single Langmuir probe consist of one electrode which is inserted in the Plasma and used to measure current through the probe as a function of the difference of the potential. These values are current can be use full to diagnose the other basic parameters of Plasma like floating potential, electron temperature, electron density and electron saturation current.

2. Double Langmuir Probe:
It has two electrodes with same diameter and equal surface area with a small gap between these electrodes. Double Langmuir Probe with an electronic circuit for giving the bias voltage is developed for determining the current-voltage characteristics and from these characteristics other parameters has to calculate. Constructional view and experimental results are given in this paper. Langmuir Probe with electronic circuit is given in fig:

Fig3. Double Langmuir Probe with electronic circuit [6]

In this experiment, Double Langmuir Probe was made of tungsten electrode with pointed tip collecting the positive ions or electrons depending on the condition applied.

3. Triple Langmuir Probe:
Triple Langmuir probe consist of three electrodes with same surface area and same gap between electrodes. It is designed to measure very accurate current voltage characteristics and using these curves, other parameters can also calculate. Triple Langmuir probe is very complicated because of its construction and measurements are not easy to calculate.

b. Probe Parameter and Plasma Parameter Calculation:

<table>
<thead>
<tr>
<th>Design Parameters</th>
<th>Langmuir Probe</th>
</tr>
</thead>
<tbody>
<tr>
<td>Insertion Length</td>
<td>215 mm</td>
</tr>
<tr>
<td>Tip Radius</td>
<td>1.5 mm</td>
</tr>
</tbody>
</table>
**Electron Temperature:** Electron temperature can be found by exploiting the linearity of the second region temperature can be realized as the reciprocal of the slop of the measured line in this region and also from the Plasma potential and floating potential. Plasma electron temperature is calculated in second region of the current-voltage characteristics (Fig 1) Expression used for temperature calculation is:

\[ T_e = \frac{2(V_s - V_f)e}{k \ln \left( \frac{2M}{\pi m} \right)} \]

**Electron Saturation current:** electron saturation current can be found at the time when we applied bias voltage much greater than the Plasma potential. In this case almost all the velocity will reach the collector and from here current – voltage characteristics has to be plotted. It is given by

\[ \ln[I_{probe} - I_{sat}] = \frac{Q}{kT_e}(V_{bias} - V_f) \]

**Electron Density:** Electron density is depending upon the electron temperature. A assignment of non-Maxwellian electron energy distribution is difficult. One more useful parameter in this paper is the mean electron energy \( C_e \). The mean energy is known to be proportional to the second derivative of the electron current with respect to the voltage. By finding the mean electron energy, the electron density can be found from given expression

\[ n_e = \frac{4 \times I_{sat}}{e \times A_p \times C_e} \]

The mean energy for a Maxwellian distribution is given,

\[ C_e = \sqrt{\frac{8kT_e}{\pi m}} \]

Where-

- \( T_e \) = Electron temperature
- \( V_s \) = Plasma voltage
- \( V_f \) = Floating potential
- \( M \) = Ion mass
- \( e \) = Electron charge
- \( m \) = Electron mass
- \( k \) = Boltzmann constant
- \( n_e \) = electron density

### 3. Experimental Setup and Experiment-

**Block diagram for setup:**

![Block diagram](image)

**Experimental setup:**

Full wave rectifier is used to convert AC power in DC source. DC power supply is given to electrodes placed inside the chamber to generate the plasma between two electrode plates. Plasma current and voltage is measured across the resistor that is connected with Langmuir Probe. Current is measured across the resistance of 10kohm connected in between bias voltage and two Langmuir probe. Measured current is known as probe current.

**Setup for measurement:**

![Setup for measurement](image)
4. Results-

Measured current voltage characteristic

![Graph of Current-voltage characteristic](image)

Fig5. Current-voltage characteristics of the plasma

The current-voltage characteristic of the plasma which formed using nitrogen gas.

Calculated parameters are-

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Calculated Values</th>
</tr>
</thead>
<tbody>
<tr>
<td>Floating Potential</td>
<td>12 volt</td>
</tr>
<tr>
<td>Electron Temperature</td>
<td>19.96*10^4 Kelvin</td>
</tr>
<tr>
<td>Electron Density</td>
<td>3.93*10^13 m^-3</td>
</tr>
<tr>
<td>Electron Saturation current</td>
<td>0.2467 m amp</td>
</tr>
<tr>
<td>Debye Length</td>
<td>1.856 mm</td>
</tr>
</tbody>
</table>

5. Conclusion-

In this paper, Langmuir Probe sensor has been described and developed. The main plasma parameters that can be reliably extracted from current-voltage response are electron temperature, electron density, electron saturation current and plasma potential. Variation of these parameters is obtained by varying the position of probe in plasma chamber.

Acknowledgement-

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References-


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